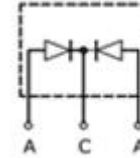
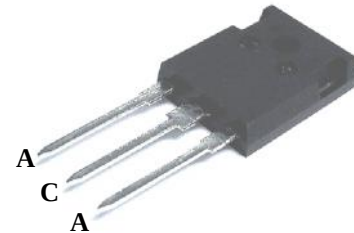


**Parallel (Common Cathode) Fast Recovery 30A,
600V Diodes in T0247 Package**
APPLICATIONS

- Switch mode power supplies (SMPS) rectifiers
- Resonant applications
- Industrial drives


FEATURES

- Fast recovery
- Soft switching
- Low reverse recovery charge
- Low forward voltage drop
- Low leakage current
- Pb-free finished; **RoHS compliant**


MAXIMUM RATINGS (per diode)

Parameter	Symbol	Value	Units
Repetitive peak reverse voltage	V_{RRM}	600	V
Continuous forward current $T_c = 25^\circ\text{C}$ $T_c = 90^\circ\text{C}$	I_F	50 30	A
Surge non-repetitive forward current $T_c = 25^\circ\text{C}$, $t_p = 10$ ms, sine halfwave	I_{FSM}	117	
Maximum repetitive forward current $T_c = 25^\circ\text{C}$, t_p limited by T_{jmax} , $D = 0.5$	I_{FRM}	81	
Soldering temperature Wave soldering, 1.6 mm (0.063 in.) from case for 10s	T_s	260	$^\circ\text{C}$
Operating junction and storage temperature	T_j, T_{stg}	-55... +150	$^\circ\text{C}$

Thermal Characteristics (per diode)

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case	R_{thJC}	1.05	$^\circ\text{C/W}$

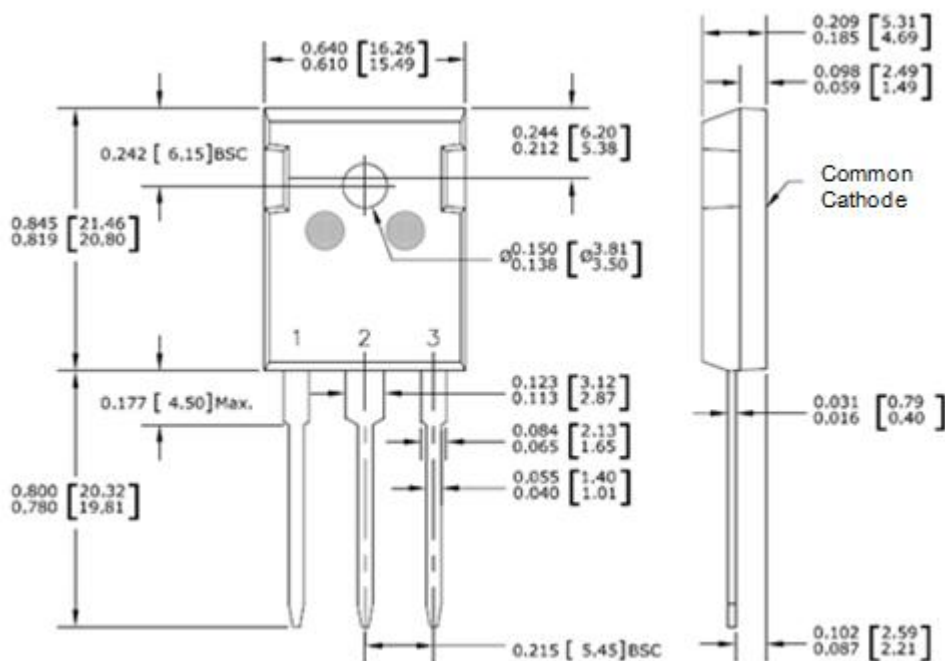
Electrical Characteristics (per diode), at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Static Characteristics					
Reverse leakage current V _R = 600V, T _j = 25°C V _R = 600V, T _j = 175°C	I _R	- -	- -	50 2500	μA
Forward voltage drop I _F = 30A, T _j = 25°C I _F = 30A, T _j = 175°C	V _F	- -	1.5 1.5	2.0 -	V

Electrical Characteristics (per diode), at $T_J = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Dynamic Characteristics					
Reverse recovery time V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 25°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 125°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 175°C	t _{rr}	- - -	126 171 178	- - -	ns
Peak reverse current V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 25°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 125°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 175°C	I _{rm}	- - -	19 22 24	- - -	A
Reverse recovery charge V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 25°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 125°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 175°C	Q _{rr}	- - -	1100 1950 2150	- - -	μC
Peak rate of fall of reverse recovery current during t _b V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 25°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 125°C V _R = 400V, I _F = 30A, di _F /dt = 1000A/μs, T _J = 175°C	dl _{rr} / dt	- - -	4.0 4.6 4.8	- - -	A/μs

Package Outline Drawing



Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**